

#### **Features**

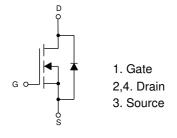
- Trench Power MV MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low R<sub>DS(on)</sub>
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Maximum Ratings**

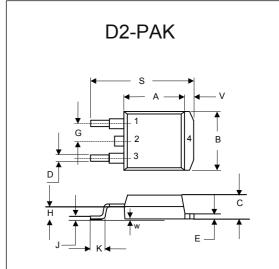
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 1.3°C/W Junction to Case

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V <sub>DS</sub>	100	V
Gate-Source Volltage		V <sub>GS</sub>	±25	V
Continuous Drain Current	T <sub>C</sub> =25°C		70	Α
	T <sub>C</sub> =100°C	l <sub>D</sub>	49	Α
Pulsed Drain Current		I <sub>DM</sub>	240	Α
Single Pulse Avalanche Energy		E <sub>AS</sub>	530	mJ
Total Power Dissipation		P <sub>D</sub>	115	W

#### **Internal Structure**

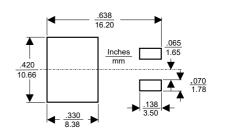


# N-CHANNEL MOSFET



DIMENSIONS					
DIM INCH		HES	HES MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOIL
Α	0.331	0.370	8.40	9.40	
В	0.378	0.417	9.60	10.60	
С	0.165	0.189	4.20	4.80	
D	0.027	0.037	0.68	0.94	
Е	0.045	0.055	1.14	1.40	
G	0.010		2.54		TYP.
Н	0.096	0.134	2.43	3.40	
J	0.011	0.025	0.28	0.64	
K	0.071	0.131	1.80	3.32	
S	0.575	0.625	14.60	15.87	
V	0.042	0.058	1.07	1.47	
W	0.000	0.010	0.00	0.25	

#### Suggested Solder Pad Layout





# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

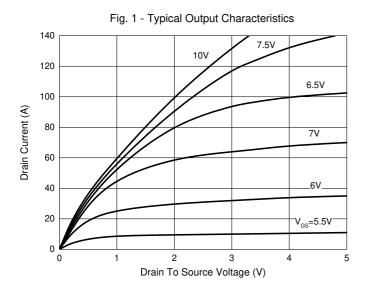
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_D = 250 \mu A$	100			V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±25V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V			1	μΑ
Gate-Threshold Voltage <sup>(Note 1)</sup>	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-Resistance <sup>(Note 1)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =12A		14.5	18	mΩ
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =12A		0.8	1.2	V
Continuous Body Diode Current	Is				70	Α
Dynamic Characteristics (Note 2)						
Input Capacitance	C <sub>iss</sub>			2960		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,f=1MHz		142		
Reverse Transfer Capacitance	C <sub>rss</sub>			120		
Total Gate Charge	$Q_g$			80		
Gate-Source Charge	$Q_{gs}$	$V_{DD} = 50V, V_{GS} = 10V, I_D = 12A$		12		·- C
Gate-Drain Charge	$Q_{gd}$			25		nC
Reverse Recovery Chrage	$Q_{rr}$	V <sub>R</sub> =50V, I <sub>F</sub> =12A, dI <sub>F</sub> /dt=100A/μs		33		
Reverse Recovery Time	t <sub>rr</sub>	ν <sub>R</sub> =50 ν, ι <sub>F</sub> =12Α, αι <sub>F</sub> /αι-100Α/μS		54		
Turn-On Delay Time	t <sub>d(on)</sub>			13		
Turn-On Rise Time	t <sub>r</sub>	$V_{GS}=10V, V_{DD}=50V, I_{D}=12A,$		14		ns
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{GEN}$ =1 $\Omega$		25		
Turn-Off Fall Time	t <sub>f</sub>			10		

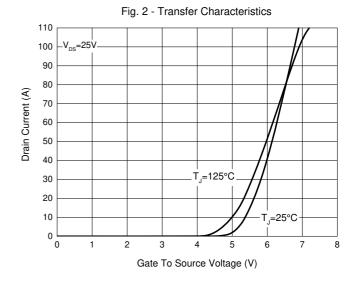
Note 1. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤2%.

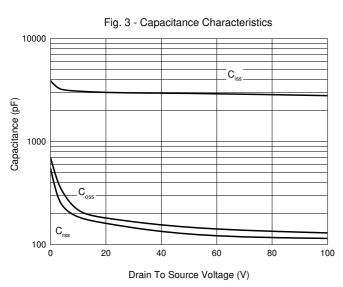
<sup>2.</sup> Guaranteed by Design, Not Subject to Production Testing.

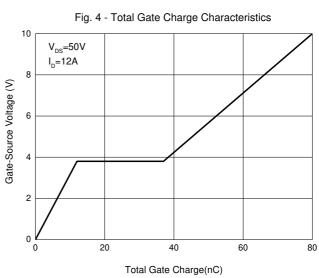


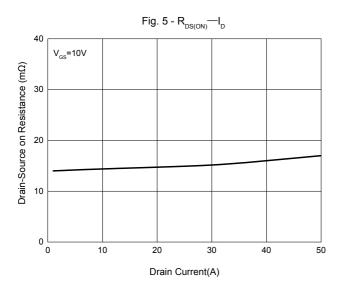
### **Curve Characteristics**

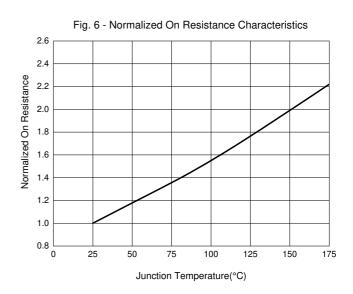














## **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel: 800pcs/Reel

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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